

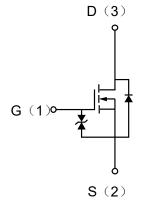
N-Channel MOSFET

Description

 $PNM723T703E0-2 \ is \ designed \ for \ high \ speed \ switching \ applications$

The enhancement mode MOS is extremely high density cell and low on-resistance.

| MOSFET Product Summary | | | | |
|------------------------|---------------------------|-----------------|--------------------|--|
| V _{DS} (V) | $R_{DS(on)}(\Omega)$ | $V_{GS(th)}(V)$ | I _D (A) | |
| 40 | 7.5@ V _{GS} =10V | 0.5 to 1.5 | 0.18 | |



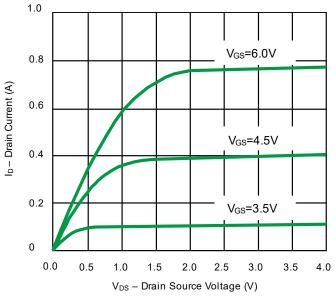
Electrical characteristics per line@25℃ (unless otherwise specified)

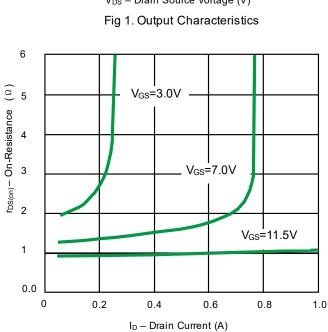
| Parameter | Symbol | Conditions | Min. | Тур. | Max. | Units |
|-----------------------------------|---------------------|--|------|------|------|-------|
| OFF CHARACTERISTICS | | | | | | |
| Drain-Source Breakdown Voltage | V _{DSS} | I _D =10μΑ,V _{GS} =0V | 40 | - | - | V |
| Zero Gate Voltage Drain Current | I_{DSS} | V _{DS} =40V,V _{GS} =0V | - | - | 0.5 | μA |
| Gate-Body Leakage Current | I _{GSS} | $V_{DS} = 0V, V_{GS} = \pm 20V$ | - | - | ±10 | μA |
| Gate Threshold Voltage | $V_{GS(th)}$ | $V_{DS} = V_{GS}$, $I_D = 250 \mu A$ | 0.5 | - | 1.5 | V |
| 01 15 D 1 0 D 1 1 | R _{DS(ON)} | $V_{GS}=5V$, $I_{D}=0.05A$ | - | - | 7.5 | Ω |
| Static Drain-Source On-Resistance | | V _{GS} =10V, I _D =0.5A | - | - | 7.5 | Ω |
| DYNAMIC PARAMETERS | | | | | | |
| Input Capacitance | C _{ISS} | | - | 1 | 40 | pF |
| Output Capacitance | C_{DSS} | V_{GS} =0V, V_{DS} =25V, f=1MHz | - | - | 20 | pF |
| Reverse Transfer Capacitance | C _{RSS} | I— I IVII IZ | - | - | 5 | pF |
| SWITCHING PARAMETERS | | | | | | |
| Turn-On Delay Time | t _{d(on)} | V_{DS} =30V, V_{GS} =10V, R_{G} =25 Ω , R_{L} =150 Ω | - | - | 20 | ns |
| Turn-Off Delay Time | t _{d(off)} | $I_D = 0.2A$ | - | - | 20 | ns |

Absolute maximum rating@25℃

| Rating | | Symbol | Value | Units |
|-------------------------|-------------------------------|-----------------|-------|-------|
| Drain-Source Voltage | | V _{DS} | 40 | V |
| Gate-Source Voltage | /oltage V _{GS} ±20 V | | V | |
| Drain Current | Continuous | l _D | 0.18 | Α |
| | Pulsed | l _D | 0.36 | А |
| Total Power Dissipation | T _A =25℃ | P _D | 150 | mW |

Typical Characteristics





 $Fig\ 3.\ On\hbox{-Resistance}\ vs.\ Drain\ Current$

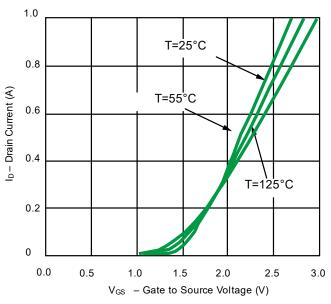


Fig 2. Transfer Characteristics

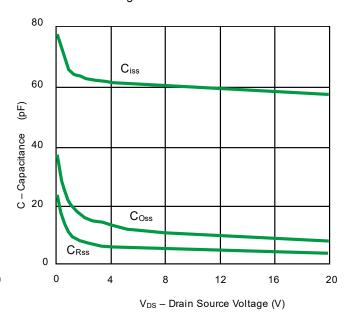
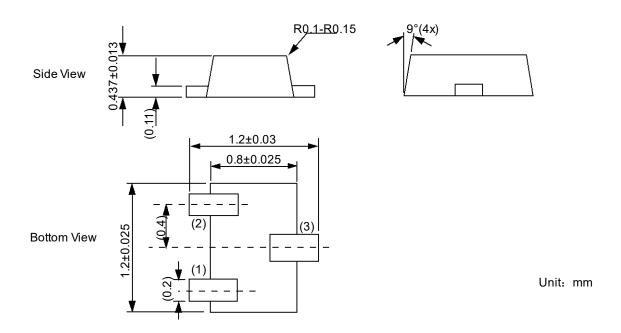
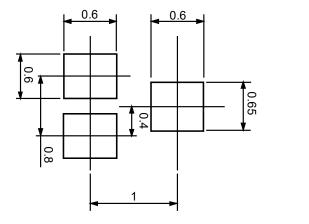


Fig 4. Capacitance

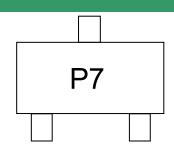
Unit: mm

Product dimension (SOT-723)





Marking information



Ordering information

| Device | Package | Reel | Shipping |
|----------------|-------------------|------|---------------------|
| PNM723T703E0-2 | SOT-723 (Pb-Free) | 7" | 10000 / Tape & Reel |

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